

Behaviour of zero modes for a one-dimensional Dirac operator arising in models of graphene

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PEP programme, Isaac Newton Institute

Joint work with Michael Levitin (Reading) and Iosif Polterovich (Montreal)

A brief word from our sponsors.

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- Operators: straightforward 2×2 systems of first order odes.
- Methods: largely classical (hope to mention some ideas).
- Properties: some show remarkably subtle dependence on properties of the potential.

Graphene

Graphene has a (2-dimensional hexagonal) periodic structure. Bloch analysis of the tight binding model leads to a dispersion relation with “Dirac cones”. The Fermi level sits at the tips of these cones; this allows a massless Dirac operator

$$-i\sigma_1\nabla_x - i\sigma_2\nabla_y + U(x, y)$$

to be used as the Hamiltonian when modeling the propagation of a free electron within a graphene layer (at least at low energies).

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$U(x, y)$ is an external (electric) potential (this can be easily realised with an electrostatic gate placed on top of the graphene layer).

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Zero energy bound states of $T_{k,V}$, or *zero modes*, correspond to conduction modes along the waveguide; want to determine when

$T_{k,V}\psi = 0$ has a non-trivial solution $\psi = \begin{pmatrix} \psi_1 \\ \psi_2 \end{pmatrix} \in L^2$.

Two spectral problems

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Remark. Since

$$T_{k,V} = T_{0,V} + k\sigma_3 \quad \text{and} \quad T_{k,\gamma V} = T_{k,0} + \gamma V,$$

K_V and Σ_V are the spectra of the linear operator pencils $k \mapsto T_{0,V} + k\sigma_3$ and $\gamma \mapsto T_{k,0} + \gamma V$ respectively.

Definition of the operator

Case $V \equiv 0$: viewing $T_{k,0}$ as a multiplication operator in Fourier space we get a closed unbounded operator with $\text{dom}(T_{k,0}) = H^1$ and $T_{k,0}^* = T_{\bar{k},0}$. The (usual) spectrum is

$$\text{spec}(T_{k,0}) = \text{spec}_{\text{ess}}(T_{k,0}) = \{\pm\sqrt{\xi^2 + k^2} : \xi \in \mathbb{R}\}.$$

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Potential classes: let $c_0(L^2)$ denote those functions $V : \mathbb{R} \rightarrow \mathbb{R}$ which are locally L^2 and satisfy

$$\|V\|_{L^2((x-1, x+1))} \rightarrow 0 \quad \text{as } |x| \rightarrow \infty.$$

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Multiplication by $V \in c_0(L^2)$ defines a compact map $H^1 \rightarrow L^2$ and hence a relatively compact perturbation of $T_{k,0}$;

$T_{k,\gamma V} = T_{k,0} + \gamma V$ can then be defined as a closed operator with $\text{dom}(T_{k,\gamma V}) = H^1$ and $T_{k,\gamma V}^* = T_{\bar{k},\bar{\gamma}V}$.

Theorem

For $V \in c_0(L^2)$ we have:

- $K_V = i\mathbb{R} \cup K_{V,d}$ where $K_{V,d}$ is a discrete subset of $\mathbb{C} \setminus i\mathbb{R}$ consisting of eigenvalues with geometric multiplicity 1 which can only accumulate along $i\mathbb{R}$.
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Proof uses the compactness of $V : H^1 \rightarrow L^2$ and the equivalences

- $k \in K_V \iff -k \in \text{spec}(\sigma_3(T_{0,0} + V))$.
- $\gamma \in \Sigma_V \iff -1/\gamma \in \text{spec}(VT_{k,0}^{-1})$.

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The bound on the geometric multiplicity follows from the fact that the eigenvalue equation is an ode.

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We will henceforth assume $k > 0$ when considering Σ_V .

γ -spectrum

If V is single-signed we have

$$\gamma \in \Sigma_V \iff -1/\gamma \in \text{spec}(\text{sgn}(V)\sqrt{|V|}T_{k,0}^{-1}\sqrt{|V|});$$

we have a self-adjoint problem!

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If $V \in C_0(L^2)$ is single-signed then $\Sigma_V \subset \mathbb{R}$.

For general (variable sign) V the set Σ_V may contain non-real points (easily seen in numerical examples). Furthermore

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Can be proved using a fairly direct argument based on symmetries.

Estimates; upper bounds

To estimate the distribution of points in Σ_V we consider the number of points inside a disc $\{z \in \mathbb{C} : |z| \leq R\}$ of radius $R \geq 0$.

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$$\#(\Sigma_V \cap \{z \in \mathbb{C} : |z| \leq R\}) \leq C_p \|V\|_{L^p}^p R^p$$

for any $R \geq 0$, where C_p depends only on p (can take $C_1 = 4e/\pi$).

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Several other approaches are almost certainly possible!

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Suppose $V \in \ell^1(L^2)$. Then

$$\#(\Sigma_V \cap [0, R]) \geq \frac{R}{\pi} \left| \int_{\mathbb{R}} V(x) dx \right| + o(R)$$

as $R \rightarrow \infty$. The same estimate holds for $\#(\Sigma_V \cap [-R, 0])$.

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- If $\int_{\mathbb{R}} V(x) dx \neq 0$ then $\Sigma_V \cap \mathbb{R}$ contains infinitely many points.
- There are limits to possible improvements for a general lower bound; for example, $\Sigma_V \cap \mathbb{R} = \emptyset$ for anti-symmetric potentials.

Asymptotics I

For any $V \in \ell^1(L^2)$ we have asymptotic upper and lower bounds on $\#(\Sigma_V \cap [0, R])$ of

$$C \frac{R}{\pi} \int_{\mathbb{R}} |V(x)| dx \quad \text{and} \quad \frac{R}{\pi} \left| \int_{\mathbb{R}} V(x) dx \right|$$

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The upper and lower bounds are closest for single-signed potentials.

Another class of potentials: let BV_0 denote functions of bounded variation with compact support. We say $V \in BV_0$ has *no gaps* if

$$|(\text{co}(\text{ess sup}(V))) \cap V^{-1}(0)| = 0.$$

Theorem

Suppose V satisfies one of

- (i) $V \in \ell^1(L^2)$ is single-signed.
- (ii) $V \in BV_0$ has no-gaps.

Then

$$\#(\Sigma_V \cap [0, R]) = \frac{R}{\pi} \left| \int_{\mathbb{R}} V(x) dx \right| + o(R)$$

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We can equivalently express this result as an asymptotic formula for points in $\Sigma_V \cap \mathbb{R}$; if $0 < \gamma_1 < \gamma_2 < \dots$ denotes the sequence of positive points in Σ_V then

$$\gamma_n = \frac{\pi}{\|V\|_{L^1}} n + o(n) \quad \text{as } n \rightarrow \infty.$$

One gap potentials: preliminaries I

We say $V \in BV_0$ has *one gap* if $V = V_1 + V_2$ for non-zero $V_1, V_2 \in BV_0$ which have no gaps and disjoint supports.

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For $j = 1, 2$ set $\text{supp}(V_j) = [a_j, b_j]$ and $v_j = \int_{\mathbb{R}} V_j(x)dx$.

Assume $b_1 < a_2$ and $\int_{\mathbb{R}} V(x)dx = v_1 + v_2 \neq 0$.

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- $\alpha \in (0, 1)$ gives a measure of the gap length.
- $\beta \geq 0$ gives a measure of the relative sizes of v_1 and v_2 .
 $\beta \in [0, 1)$ if $v_1 v_2 > 0$ and $\beta > 1$ if $v_1 v_2 < 0$.

One gap potentials: preliminaries II

When $\alpha\beta > 1$ define

$$\nu_{\alpha,\beta} = \frac{2}{\pi} \left[\beta \arcsin \frac{\sqrt{\alpha^2\beta^2 - 1}}{\sqrt{\beta^2 - 1}} + \arcsin \frac{\sqrt{1 - \alpha^2}}{\alpha\sqrt{\beta^2 - 1}} \right].$$

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If β is positive and rational write $\beta = p/q$ where $p, q \in \mathbb{N}$ are coprime. If p and q are both odd set $p_\beta = p$ and $q_\beta = q$; if p and q have opposite parity set $p_\beta = 2p$ and $q_\beta = 2q$.

One gap potentials: preliminaries II

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Set

$$A(\alpha, \beta) = \begin{cases} 1 & \text{if } \alpha\beta < 1, \\ \nu_{\alpha,\beta} & \text{if } \alpha\beta > 1 \text{ and } \beta \notin \mathbb{Q}, \\ \frac{4}{q_\beta} \left[\frac{1}{4}(p_\beta + q_\beta \nu_{\alpha,\beta}) \right] - \frac{p_\beta}{q_\beta} + \frac{2}{q_\beta} & \text{if } \alpha\beta > 1 \text{ and } \beta \in \mathbb{Q}; \end{cases}$$

($\lfloor x \rfloor$ denotes the largest integer which is less than x)

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Theorem

Let $V \in BV_0$ be a one-gap potential with $\int_{\mathbb{R}} V(x) dx \neq 0$. Suppose $\alpha\beta \neq 1$. If $\alpha\beta > 1$ and $\beta \in \mathbb{Q}$ suppose additionally that $p\beta + q\beta\nu_{\alpha,\beta} \notin 4\mathbb{Z}$. Then

$$\#(\Sigma_V \cap [0, R]) = \frac{1}{\pi} A(\alpha, \beta) |v_1 + v_2| R + o(R)$$

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For different V we can obtain an asymptotic formula

$$\#(\Sigma_V \cap [0, R]) = \frac{C}{\pi} R + o(R) \quad (1)$$

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Theorem

Let $0 < v < A < u$. Then there exists a piecewise constant one-gap potential V such that $|\int_{\mathbb{R}} V(x) dx| = v$, $\|V\|_{L^1} = u$ and (1) holds with $C = A$.

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Define a differentiable function $\Delta_V : \mathbb{R} \rightarrow \mathbb{R}$ by

$$\Delta_V(\lambda) = [\theta_\gamma^+(+\infty) - \theta_\gamma^+(0)] + [\theta_\gamma^-(0) - \theta_\gamma^-(-\infty)].$$

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- If V is single-signed then $\Delta_V(\gamma)$ is monotonic in γ , strictly increasing (resp., decreasing) if $V \geq 0$ (resp., $V \leq 0$).
- If $V \in BV_0$ has no gaps then, for $n = 0, 1, 2$,

$$\frac{d^n}{d\gamma^n} \left(\Delta_V(\gamma) - \gamma \int_{\mathbb{R}} V(x) dx \right) = o(1) \quad \text{as } \gamma \rightarrow \infty.$$

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- Prove the result for $\phi \equiv 0$, then show the addition of ϕ only changes $N_0(R)$ by $o(R)$.

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where

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Case $\beta \in \mathbb{Q}$: (easier!). Periodicity and condition $p_\beta + q_\beta \nu_{\alpha,\beta} \notin 4\mathbb{Z}$ ensures zeros of f_0 are uniformly transversal. Conditions on ϕ ($n = 0, 1$) then means number of zeros is unchanged for sufficiently large x .

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- A uniform lower bound on $|f_0(x)| + |f_0'(x)| + |f_0''(x)|$ and the conditions on ϕ ensures the number of zeros changes by at most 2 near each such turning point for sufficiently large x .

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- For $V \in \ell^1(L^2)$ can obtain bounds on $\#(K_{V,d} \cap (\epsilon, \infty))$ for a fixed $\epsilon > 0$ (these bounds diverge as $\epsilon \rightarrow 0^+$).

Central potentials

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- Compare with Calogero's bound for Schrödinger operators with central potentials.

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$$\#(K_{V,d} \cap \mathbb{R}^+) = \left\lfloor \frac{1}{2} + \frac{1}{\pi} \int_{\mathbb{R}} V(x) dx \right\rfloor.$$

- Compare with Calogero's bound for Schrödinger operators with central potentials.
- If V is central is it the case that $K_{V,d} \subset \mathbb{R}$?

Central potentials

We say that $V \in \ell^1(L^2)$ is a *central* potential if there exists $x_0 \in \mathbb{R}$ such that V is increasing on $(-\infty, x_0]$ and decreasing on $[x_0, \infty)$.

Theorem

Suppose $V \in \ell^1(L^2)$ is central. Then

$$\#(K_{V,d} \cap \mathbb{R}^+) = \left\lfloor \frac{1}{2} + \frac{1}{\pi} \int_{\mathbb{R}} V(x) dx \right\rfloor.$$

- Compare with Calogero's bound for Schrödinger operators with central potentials.
- If V is central is it the case that $K_{V,d} \subset \mathbb{R}$?
- Gaps (or dips) in a potential can alter the picture radically. For a potential consisting of two square steps separated by a gap of length g numerics give $\#K_{V_g,d} = O(g)$ as $g \rightarrow +\infty$ (however $\#(K_{V_g,d} \cap \mathbb{R})$ seems to remain bounded).